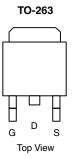


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COMPLIANT

N-Channel 60 V (D-S) MOSFET

PRODUCT SUMMARY			
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)	Q _g (Тур)
60	0.0044 at V_{GS} = 10 V	90 ^d	105



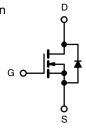
Ordering Information: SUM90N06-4m4P-E3 (Lead (Pb)-free)

FEATURES

- TrenchFET[®] Power MOSFET
- 175 °C Junction Temperatur
- 100 % R_{g} and UIS Tested ٠
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Power Supply - Secondary Synchronous Rectification
- Industrial
- OR-ing



N-Channel MOSFET

Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	60	v	
Gate-Source Voltage		V _{GS}	± 20	- v	
Continuous Drain Current ($T_1 = 175 °C$)	T _C = 25 °C		90 ^d		
Continuous Drain Guirent $(T_j = 175 \text{ G})$	T _C = 70 °C	I _D	90 ^d	А	
Pulsed Drain Current		I _{DM}	240		
Avalanche Current		I _{AS}	70		
Single Avalanche Energy ^a	L = 0.1 mH	E _{AS}	245	mJ	
	T _C = 25 °C	Р	300 ^b	14/	
Maximum Power Dissipation ^a	T _A = 25 °C ^c	– P _D –	3.75	W	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Limit	Unit	
Junction-to-Ambient (PCB Mount) ^c	R _{thJA}	40	°C/W	
Junction-to-Case (Drain)	R _{thJC}	0.5	0.00	

Notes:

a. Duty cycle \leq 1 %.

b. See SOA curve for voltage derating.

c. When mounted on 1" square PCB (FR-4 material).

d. Package limited.

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Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Drain-Source Breakdown Voltage	V _{DS}	$V_{DS} = 0 V, I_{D} = 250 \mu A$	60			- V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$	2.5		4.5	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 250	nA
Zero Gate Voltage Drain Current		$V_{DS} = 60 V, V_{GS} = 0 V$			1	
	I _{DSS}	$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$			50	μA
		$V_{DS} = 60 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ T}_{J} = 150 ^{\circ}\text{C}$			250	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 10 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$	70			Α
Drain-Source On-State Resistance ^a	R.	V _{GS} = 10 V, I _D = 20 A		0.0036	0.0044	0
	R _{DS(on)}	V_{GS} = 10 V, I _D = 20 A, T _J = 125 °C		0.0059	0.0077	Ω
Forward Transconductance ^a	9 _{fs}	V _{DS} = 15 V, I _D = 20 A		60		S
Dynamic ^b				•		
Input Capacitance	C _{iss}	V _{GS} = 0 V, V _{DS} = 30 V, f = 1 MHz		6190		pF
Output Capacitance	C _{oss}			990		
Reverse Transfer Capacitance	C _{rss}			340		
Total Gate Charge ^c	Qg			105	160	nC
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 30$ V, $V_{GS} = 10$ V, $I_{D} = 85$ A		29		
Gate-Drain Charge ^c	Q _{gd}			28		
Gate Resistance	R _g	f = 1 MHz		1.4	2.8	Ω
Turn-On Delay Time ^c	t _{d(on)}			23	35	
Rise Time ^c	t _r	$V_{DD} = 30 \text{ V}, \text{ R}_{\text{L}} = 0.4 \Omega$ $\text{I}_{\text{D}} \cong 85 \text{ A}, \text{ V}_{\text{GEN}} = 10 \text{ V}, \text{ R}_{\text{g}} = 1 \Omega$		15	25	ns
Turn-Off Delay Time ^c	t _{d(off)}			36	55	
Fall Time ^c	t _f			8	15	
Source-Drain Diode Ratings and Cha	aracteristics (T _C = 25 °C) ^b				
Continuous Current	۱ _S				85	
Pulsed Current	I _{SM}				240	A
Forward Voltage ^a	V _{SD}	$I_{F} = 30 \text{ A}, V_{GS} = 0 \text{ V}$		0.84	1.5	V
Reverse Recovery Time	t _{rr}			61	100	ns
Peak Reverse Recovery Current	I _{RM(REC)}	I _F = 75 A, di/dt = 100 A/μs		3.0	4.5	Α
Reverse Recovery Charge	Q _{rr}			91	140	μC

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

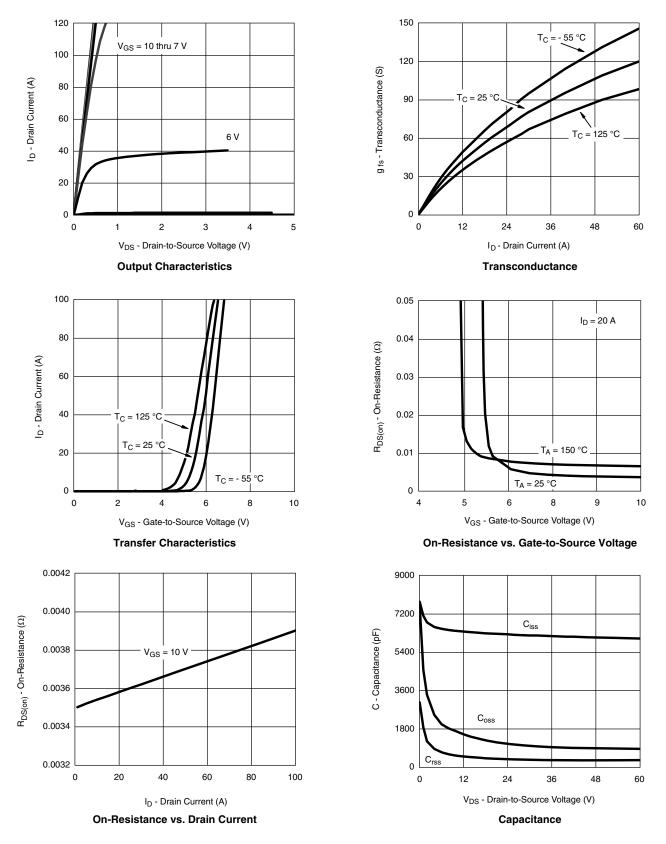
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



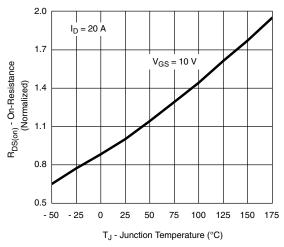
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For technical questions, contact: pmostechsupport@vishay.com

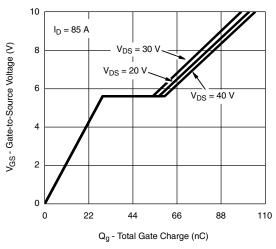
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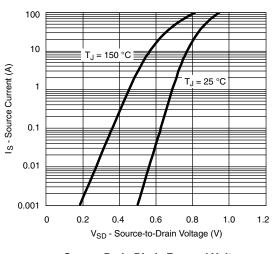
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



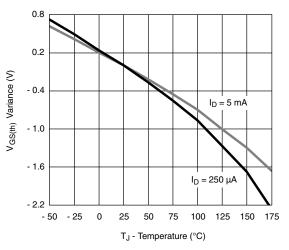
On-Resistance vs. Junction Temperature



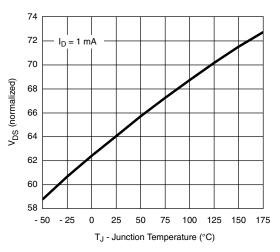




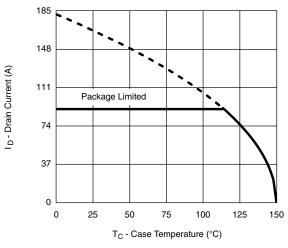
Source-Drain Diode Forward Voltage



Threshold Voltage



On-Resistance vs. Junction Temperature



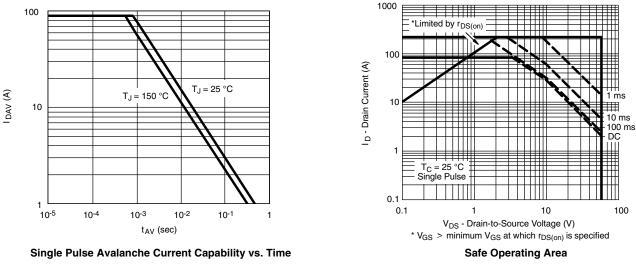
Maximum Drain Current vs. Case Temperature

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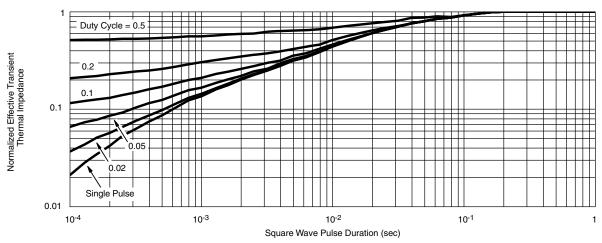
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TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

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